



Reliability Test Report

Product Name: CA-IS1311X

Report Version: V1.1



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1. Overview

Reliability testing of microelectronic products is a risk mitigation process designed to ensure the service life of device in customer applications. Semiconductor wafer manufacturing process and package-level reliability can be assessed in a variety of ways and may include accelerated environmental test conditions. Chipanalog evaluates manufacturability of the device to verify a robust silicon and assembly flow to ensure continuity of supply to customers. Chipanalog qualifies new devices, significant changes, and product families based on JEDEC JESD47.

2. Part Number List

Package Type	Part Number
SOIC8-WB(G)	CA-IS1311G/CA-IS1311BG

Note: JEDEC specification is designed to also qualify a family of similar components utilizing the same fabrication process, design rules, and similar circuits. The family qualification may also be applied to a package family where the construction is the same and only the size and number of leads differs.

3. Product Information

3.1. Wafer Information

Wafer	KUAFU, PANLONG, FUXI	
Fab Process	18BCD	

3.2. Package Information

Assembly site	JCET
FT site	JCET
Package	SOIC8-WB
Lead frame	Cu
Bond wire	20um Au
MSL level	MSL3



4. Reliability Qualification Plan

4.1. Device Qualification Test Requirements

Stress	Ref.	Abbv.	Conditions	Duration /Accept
Electrical Parameter	JESD86	ED	Per Datasheet	Per Datasheet
Assessment	723000			
High Temperature	JESD22-A108,	HTOL	T _J ≥ 125°C	1000 hrs/0 Fail
Operating Life	JESD85	HIOL	Vcc ≥Vcc max	
Human Body Model	JS-001	ESD-	T _A = 25°C	Classification
ESD	13-001	HBM	1A = 25 C	Classification
Charged Device	JS-002	ESD	T _A = 25°C	Classification
Model ESD	J3-002	CDM		
Latch-Up	JESD78	LU	Class I or Class II	Classification

4.2. Nonhermetic Package Qualification Test Requirements

Stress	Ref.	Abbv.	Conditions	Duration /Accept
MSL Preconditioning	JESD22-A113	PC	Per appropriate MSL level per J-STD-020	Electrical Test (optional)
High Temperature Storage	JESD22-A103 & A113	HTSL	150°C, 1000 hrs	1000 hrs/0 Fail
Temperature Humidity Bias	JESD22-A101	ТНВ	85°C, 85% RH, V _{CC} max	1000 hrs/0 Fail
Highly Accelerated Temperature and Humidity Stress	JESD22-A110	HAST	130°C/110°C, 85% RH, V _{CC} max	96/264 hrs/0 Fail
Temperature Cycling	JESD22-A104	TC	-65°C to 150°C	500 cycles/0 Fail
Unbiased Temperature/Humidity	JESD22-A102	AC	121°C/100% RH	96 hrs/0 Fail
Unbiased Temperature/Humidity	JESD22-A118	UHAST	130°C/110°C, 85% RH	96/264 hrs/0 Fail
Bond Pull Strength	M2011	BPS	Characterization, Pre Encapsulation	Ppk≥1.66 or Cpk≥1.33
Bond Shear	JESD22-B116	BS	Characterization, Pre Encapsulation	Ppk≥1.66 or Cpk≥1.33
Solderability	JESD22-B102	SD	Characterization	95% coverage

Note: Either HAST or THB may be chosen. Either HAST or THB may be chosen. If THB or HAST is run, then UHAST need not be run. Autoclave is not recommended as a qualification test; Unbiased or biased HAST is the recommended stress and is required for organic substrates instead of Autoclave.



5. Reliability Test Results

5.1. Device Reliability Test Results

Stress	Condition	Duration	Sample Size	Result	Classification
ED	Per Datasheet	/	10*3 lots	Pass	/
HTOL	T _A = 135°C, V _{CC} = 5.5V	1000 hrs	77*3 lot	Pass	/
ESD-HBM	$T_A = 25^{\circ}C$	/	3*1 lot	Pass	Class 3A
ESD-CDM	$T_A = 25^{\circ}C$	/	3*1 lot	Pass	Class C3
LU	$T_A = 25^{\circ}C$	/	3*1 lot	Pass	Class I A

Note: 1 lot HTOL test data comes from qualification of CA-IS1311G, another 2 lot HTOL test data come from qualification of CA-IS12XX&CA-IS13XX series.

5.2. Package Reliability Test Results

Stress	Condition	Duration	Sample size	Results
PC	MSL 3	/	231*3 lot	Pass
HTSL	T _A = 150°C	1000 hrs	77*3 lot	Pass
HAST	130°C /85%RH, V _{CC} = 5.5V	96 hrs	77*3 lot	Pass
TC	-65°C to 150°C	500 cycles	77*3 lot	Pass
AC	121°C /100% RH	96 hrs	77*3 lot	Pass
BPS	M2011	/	30 bonds/5 ea.	Pass
BS	JESD22-B116	/	30 bonds/5 ea.	Pass
SD	Steam aging, 245°C dipping	5s	22 leads*3 lot	Pass

Note: CA-IS1311G & CA-IS1311BG share the same packaging BOM and package reliability data refer to generic data of same package family.

6. Conclusion

CA-IS1311X is qualified with JEDEC standards.



Disclaimer

This information is provided to assist customers in design and development. It could change for technology innovation without notice.

The devices are shipped after passing final test. Customers are responsible to conduct sufficient engineering and additional qualification testing to determine whether a device is suitable for use in their applications.

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Revision History

Revision	Change Log	Date
V1.0	Initial release	Jul, 2023
V1.1	Add PN CA-IS1311BG	Dec, 2023